Two-Level System Interactions with Qubits and Resonators

They're the worst.... Or are they? They are.

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Outline

- Discovery: Before 2000's
- 2 TLS Properties (and Applications?)
- 3 Avoidance Techniques

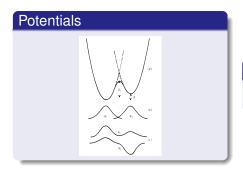


Glasses

- In the late 80's W.A. Phillips reported on experimental results analyzing two-level system affects on thermodynamic properties of solids (heat capacity and thermal conductivity).
- Then, it was postulated that systems tunneling between two available states were the cause of the anomolous behavior of the properties of glasses.^[1]



Before 2000's



Coupled Hamiltonian

$$\begin{pmatrix} E_1 + <\phi_1 | V - V_1 | \phi_1 > & <\phi_1 | H | \phi_2 > \\ <\phi_2 | H | \phi_1 > & E_2 + <\phi_2 | V - V_2 | \phi_2 > \end{pmatrix}$$

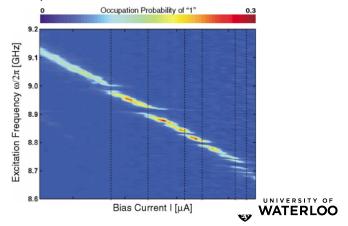


First Ideas

- Affect oscillation amplitude (Not T₁).
- Early publications emphasized first measured single TLS-qubit interaction (not bulk).^[2]
- Theory (< 2004) concluded on current coupling. [3]



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- Full warm-up and cool-down repopulates the system with TLS.
- TLS location in frequency can change spontaneously.



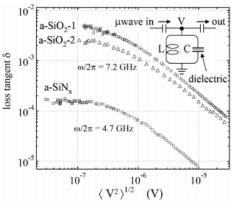
Storing Data in TLS

In 2008, the Martinis Group (UCSB) coupled a phase qubit to a two-level system. They coherently swapped arbitrary states between the qubit and the two-level system with high fidelity (79%).^[4]

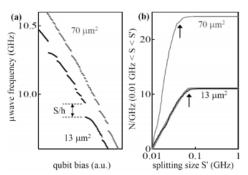
However, this is likely not to see further application (uncontrolled TLS location, other methods available, uncontrolled coupling strength, etc.)



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- Reduce junction size^[5]





WATERLOO

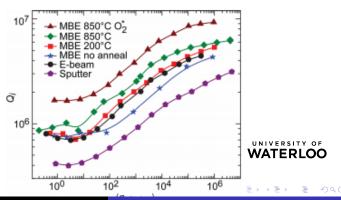
- Use Silicon-Nitride for junctions (not Si0₂)^[5]
- Reduce junction size^[5]
- Use better resonator materials^[6]

TABLE I. Fit values for $\tan \delta_{eff}$.

Metal	Dielectric	W (μm)	$tan \delta_{eff}$
Nb (poly)	Wet SiO ₂ /Si	10	2.4e-5
Nb (poly)	Si	10	1.5e-5
Nb (poly)	Sapphire	10	1.8e-5
Al (poly)	Dry SiO ₂ /Si	10	2.0e-5
Al (poly)	Si	10	1.5e-6
Al (poly)	Sapphire	10	1.6e-6
Al (epi)	Sapphire	10	1.8e-6
Re (epi)	Sapphire	10	1.8e-6
TiN (poly)	Si	10	9.6e-7
Nb (poly)	Wet SiO ₂ /Si	3	5.7e-5
Nb (poly)	Si	3	3.7e-5
Nb (poly)	Sapphire	3	2.3e-5
Al (poly)	Dry SiO ₂ /Si	3	NA
Al (poly)	Si	3	NA
Al (poly)	Sapphire	3	NA
Al (epi)	Sapphire	3	6.5e-6
Re (epi)	Sapphire	3	3.3e-6
TiN (poly)	Si	3	3.0e-6



- Use Silicon-Nitride for junctions (not Si0₂)^[5]
- Reduce junction size^[5]
- Use better resonator materials^[6]
- Use MBE deposition^[7]



References I

- Phillips, W. A. "Two-level States in Glasses." Reports on Progress in Physics 50, no. 12 (1987): 1657.
- [2] Simmonds, R. W., K. M. Lang, D. A. Hite, S. Nam, D. P. Pappas, and John M. Martinis. "Decoherence in Josephson Phase Qubits from Junction Resonators."
- [3] Martinis, John M., K. B. Cooper, R. McDermott, Matthias Steffen, Markus Ansmann, K. D. Osborn, K. Cicak, et al. "Decoherence in Josephson Qubits from Dielectric Loss." Phys. Rev. Lett. 95, no. 21 (November 2005): 210503. doi:10.1103/PhysRevLett.95.210503.

References II

- [4] Neeley, Matthew, M. Ansmann, Radoslaw C. Bialczak, M. Hofheinz, N. Katz, Erik Lucero, A. O Connell, H. Wang, A. N. Cleland, and John M. Martinis. "Process Tomography of Quantum Memory in a Josephson-Phase Qubit Coupled to a Two-Level State." Nat Phys 4, no. 7 (July 2008): 523 526. doi:10.1038/nphys972.
- [5] Martinis, John M., K. B. Cooper, R. McDermott, Matthias Steffen, Markus Ansmann, K. D. Osborn, K. Cicak, et al. "Decoherence in Josephson Qubits from Dielectric Loss." Phys. Rev. Lett. 95, no. 21 (November 2005): 210503. doi:10.1103/PhysRevLett.95.210503.

References III

- [6] Sage, Jeremy M., Vladimir Bolkhovsky, William D. Oliver, Benjamin Turek, and Paul B. Welander. "Study of Loss in Superconducting Coplanar Waveguide Resonators." Journal of Applied Physics 109, no. 6 (2011): 063915. doi:10.1063/1.3552890.
- [7] Megrant, A., C. Neill, R. Barends, B. Chiaro, Yu Chen, L. Feigl, J. Kelly, et al. "Planar Superconducting Resonators with Internal Quality Factors above One Million." Applied Physics Letters 100, no. 11 (2012): 113510. doi:10.1063/1.3693409.

